

# HiPerFET™ Power MOSFET

## **IXFR120N20**

(Electrically Isolated Tab)

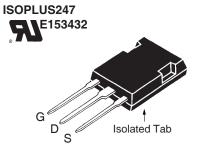
N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

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Symbol	Test Conditions	Maximum Ratings			
V <sub>DSS</sub>	$T_J = 25^{\circ}C$ to $150^{\circ}C$	200	V		
$V_{DGR}$	$T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$	200	V		
V <sub>GSS</sub>	Continuous	±20	V		
V <sub>GSM</sub>	Transient	±30	V		
I <sub>D25</sub>	T <sub>C</sub> = 25°C	105	А		
LRMS	Terminal Current Limit	76	Α		
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	480	Α		
I	$T_{c} = 25^{\circ}C$	120	Α		
I <sub>A</sub> E <sub>AS</sub>	$T_{c} = 25^{\circ}C$	3	J		
dv/dt	$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}},  V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}},  T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	5	V/ns		
P <sub>D</sub>	$T_{c} = 25^{\circ}C$	417	W		
T <sub>J</sub>		- 55 +150	°C		
T <sub>JM</sub>		150	°C		
T <sub>stg</sub>		- 55 +150	°C		
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C		
T <sub>SOLD</sub>	Plastic Body for 10s	260	°C		
V <sub>ISOL</sub>	50/60 Hz, 1 Minute	2500	V~		
F <sub>c</sub>	Mounting Force	20120/4.527	N/lb		
Weight		5	g		

Symbol $(T_J = 25^{\circ}C,$	<b>Test Conditions</b> Unless Otherwise Specified)		Chara Min.	cteristic Typ.	Values Max.	·
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 3mA$		200			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 8mA$		2.0		4.0	V
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$				±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$	T <sub>J</sub> = 125°C			100 2	μA mA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 60A, Note 1$				19.5	mΩ

 $egin{array}{lll} V_{_{DSS}} & = & 200V \ I_{_{D25}} & = & 105A \ R_{_{DS(on)}} & \leq & 19.5 m\Omega \ t_{_{rr}} & \leq & 250 ns \ \end{array}$ 



G = Gate D = DrainS = Source

### **Features**

- Silicon Chip on Direct-Copper Bond (DCB) Substrate
- Isolated Mounting Surface
- 2500V~ Electrical Isolation
- Avalanche Rated
- Fast Intrinsic Rectifier
- ${}^{\bullet}$  Low  ${\rm R_{\rm DS(ON)}}$  and  ${\rm Q_{\rm G}}$

### **Advantages**

- · Easy to Mount
- Space Savings
- High Power Density

### **Applications**

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- DC Choppers
- AC & DC Motor Controls



ISOPLUS247 (IXFR) Outline



<b>Symbo</b> (T <sub>J</sub> = 25		Test Conditions Unless Otherwise Specified)	Chara Min.	acteristic Typ.	Values Max.
g <sub>fs</sub>		$V_{DS} = 10V, I_{D} = 60A, Note 1$	40	70	S
C <sub>iss</sub>	)			9100	pF
$\mathbf{C}_{oss}$	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		2200	pF
$\mathbf{C}_{rss}$	J			1000	pF
t <sub>d(on)</sub>	)	Resistive Switching Times		40	ns
t,	Ţ	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 60A$		65	ns
$\mathbf{t}_{d(off)}$		00 20 200 2		110	ns
t <sub>f</sub>	J	$R_{_{G}} = 1\Omega$ (External)		35	ns
$\mathbf{Q}_{g(on)}$	)			360	nC
$Q_{gs}$	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 60A$		50	nC
$\mathbf{Q}_{gd}$	J			170	nC
R <sub>thJC</sub>					0.30 °C/W
$\mathbf{R}_{\mathrm{thCS}}$				0.15	°C/W

# 1 - Gate 2 - Drain C 3 - Source

# Source-Drain Diode

Symbol $(T_J = 25^{\circ}C, U)$		Chara Min.	cteristic Typ.	Values Max.	
I <sub>s</sub>	$V_{GS} = 0V$			120	Α
I <sub>sm</sub>	Repetitive, Pulse Width Limited by $T_{JM}$			480	Α
V <sub>SD</sub>	$I_{\rm F} = 100 {\rm A}, \ V_{\rm GS} = 0 {\rm V}, \ {\rm Note} \ 1$			1.5	V
$\left\{ egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} \right\}$	$I_{_{\rm F}} = 50{\rm A}, \; -{\rm di}/{\rm dt} = -100{\rm A}/{\rm \mu s}$ $V_{_{\rm R}} = -100{\rm V}, \; V_{_{\rm GS}} = 0{\rm V}$		1.1 13	250	ns µC A

Dim.	Millimeter		Inches	
Dim.	min	max	min	max
Α	4.83	5.21	0.190	0.205
A1	2.29	2.54	0.090	0.100
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b2	1.91	2.20	0.075	0.087
b4	2.92	3.24	0.115	0.128
С	0.61	0.83	0.024	0.033
D	20.80	21.34	0.819	0.840
D1	15.75	16.26	0.620	0.640
D2	1.65	2.15	0.065	0.085
D3	20.30	20.70	0.799	0.815
Е	15.75	16.13	0.620	0.635
E1	13.21	13.72	0.520	0.540
е	5.45 BSC		0.215	BSC
L	19.81	20.60	0.780	0.811
L1	3.81	4.38	0.150	0.172
Q	5.59	6.20	0.220	0.244
R	4.25	5.50	0.167	0.217
W	-	0.10	-	0.004

Note 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

